Docket No.: 60188-431
IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

<u>PATENT</u>

In re Application of

Customer Number: 20277

Akihiko ISHIBASHI, et al.

Confirmation Number: 6491

Serial No.: 10/017,389

Group Art Unit: 2818

Filed: December 18, 2001

Allowed: November 10, 2003 Examiner: Mai Huong C. Tran

For: METHOD FOR FABRICATING SEMICONDUCTOR, METHOD FOR FABRICATING SEMICONDUCTOR SUBSTRATE, AND SEMICONDUCTOR LIGHT EMITTING

DEVICE

LETTER UNDER 37 CFR 1.312

Mail Stop Issue Fee Commissioner for Patents P.O. Box 1450 Alexandria, VA 22313-1450

Sir:

We are in receipt of the Notice of Allowance dated November 10, 2003. The title, as it appears on the Notice of Allowance, is incorrect. The title should read METHOD FOR FABRICATING SEMICONDUCTOR, METHOD FOR FABRICATING SEMICONDUCTOR SUBSTRATE, AND SEMICONDUCTOR LIGHT EMITTING DEVICE. This information appeared correctly on the executed Declaration filed December 18, 2001.

It is respectfully requested that the records of the Patent Office be corrected to ensure that the deed of Letters Patent will be printed correctly.

Respectfully submitted,

MCDERMOTT, WILL & EMERY

Michael E. Fogarty

Registration No. 36,139

600 13th Street, N.W. Washington, DC 20005-3096 (202) 756-8000 MEF:blp Facsimile: (202) 756-8087

Date: December 16, 2003

WDC99 854291-1.060188.0431



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DEVICE

REQUEST FOR ACKNOWLEDGEMENT OF THE CITED ART

Mail Stop Issue Fee Commissioner for Patents P.O. Box 1450 Alexandria, VA 22313-1450

Sir:

We are in receipt of the Notice of Allowance dated November 10, 2003.

In reviewing the file, it is noted that we have not received acknowledgement of the Information Disclosure Statement and cited art filed September 17, 2003. Enclosed are copies of the Information Disclosure Statement, PTO-1449 and stamped return postcard acknowledgement.

Applicants hereby respectfully request that:

the appropriately acknowledged PTO-1449 be furnished to Applicants; and the record be clarified to confirm that the cited art has been considered and made of record.

Respectfully submitted,

MCDERMOTT, WILL & EMERY

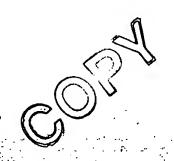
Michael F. Fogarty Registration No. 36,139

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Date: December 16, 2003

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Applicant: Akihiko ISHIBASHI, et al.	Docket No. 60188-431									
METHOD FOR FABRICATING SEMICONDUCTOR, METHOD FOR FABRICATING										
Title: SEMICONDUCTOR SUBSTRATE, AND SEMICONDUCTOR LIGHT EMITTING DEVICE Serial/Reg /Patent No. 10/017,389										
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copies of cited references	Fee Address Indication Form Q P									
☐ Preliminary Amendment	☐ Terminal Disclaimer									
Response to Missing Parts Notice	Petition to Commissioner									
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Resp. to Notice to Correct App. Papers Certified Copy of Priority Doc. Claim for Convention Priority Response/Amendment to Office Action of July 22, 2003 Request for month Extension of Time										
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THE PATENT AND TRADEMARK OFFICE DATE STAMPED HEREON IS ACKNOWLEDGEMENT THAT THE ITEMS, CHECKED ABOVE, WERE RECEIVED BY THE PTO ON THE DATE STAMPED.										



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PATENT

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DEVICE

SUPPLEMENTAL INFORMATION DISCLOSURE STATEMENT

Mail Stop DD Commissioner for Patents P.O. Box 1450 Alexandria, VA 22313-1450

Dear Sir:

In accordance with the provisions of 37 C.F.R. 1.56, 1.97 and 1.98, the attention of the Patent and Trademark Office is hereby directed to the reference listed on the attached form PTO-1449. It is respectfully requested that the reference be expressly considered during the prosecution of this application, and that the reference be made of record therein and appear among the "References Cited" on any patent to issue therefrom.

This Information Disclosure Statement ("IDS") is supplemental to the IDS filed on August 14, 2003, and includes a partial English translation of JP 10-150245 cited therein.

Please charge any shortage in fees due in connection with the filing of this paper, including extension of time fees, to Deposit Account 500417 and please credit any excess fees to such deposit account.

Respectfully submitted,

MCDERMOTT, WILL & EMERY

Michael E. Fogarty

Registration No. 36,139

600 13th Street, N.W. Washington, DC 20005-3096

(202) 756-8000 MEF:jgh Facsimile: (202) 756-8087

Date: September 17, 2003

INFORMATION DISCLOSURE CITATION IN ANO APPLICATION				60188-431 10/6			RIAL NO. 017,389					
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^{*}EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609. Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.

1 Applicant's unique citation designation number (optional). 2 Applicant is to place a check mark here if English language Translation is attached.